Laser re-melting pit technique for singlecell SRF cavity gradient pushing

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Profile Comparison before and after laser re-melting



Manmade pit



After re-melting the pit depth changed for 120um to 30 um

Laser processing of 1.3GHz single-cell cavity TE1ACC003











The Pit before re-melting

After re-melting



The Pit before re-melting

After re-melting

Images was taken from Kyoto Optical Inspection machine

Cavity TE1ACC003 vertical test result after laser processing (Eacc=39.5MV/m)



TE1ACC003 - Q vs E Test ed on 01/15/2010 compared to gradient before laser re-melting

